Localised Collective Excitations in Doped Graphene in a Strong Magnetic Field

[arXiv:0902.4176]

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What is Graphene?

- "Graphene is the name given to a single layer of carbon atoms densely packed into a benzene-ring structure"
- First isolated in 2004 by physicists at the University of Manchester, UK and the Institute for Microelectronics Technology, Chernogolovka, Russia



K.S. Novoselov *et al.*, *Science* **306**, 666 (2004)



Andre Geim





What's all the fuss?

- Fundamentally interesting physics and useful physical properties
- QED in a mesoscopic system e.g. room temperature anomalous integer quantum Hall effect

K.S. Novoselov et al, Nature 438, 197

Important applications i.e. nanoelectronics – is graphene the new silicon?



Credit: Andre Geim

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Unanswered Questions



Credit: Andre Geim

- How does substrate affect graphene properties?
- What is the nature of disorder in graphene?
- How could an energy gap be opened at the K points?
 constriction i.e. nanoribbons
 application of an electric field





Aim of Project

Single graphene sheet in a strong perpendicular magnetic field and single axially symmetric charged impurity
 corresponds to a low impurity density



High magnetic field approximation – reduce disorder broadening, so LLs well defined

• Want to find collective excitations localised on impurity





Single Particle Picture

- Single impurity at origin symmetric gauge: A=1/2 B x r
- No intervalley scattering

$$\mathbf{H}_{\mathrm{D}} = v_{\mathrm{F}} \sigma.\mathbf{p} = \hbar \frac{\sqrt{2} \mathbf{v}_{\mathrm{F}}}{\ell_{\mathrm{B}}} \begin{pmatrix} 0 & -\frac{i}{\sqrt{2}} \left(\frac{z^{\star}}{2\ell_{B}} + 2\ell_{B} \partial_{Z}\right) \\ \frac{i}{\sqrt{2}} \left(\frac{z}{2\ell_{B}} - 2\ell_{B} \partial_{Z^{\star}}\right) & 0 \end{pmatrix} = \hbar \omega_{\mathrm{c}} \begin{pmatrix} 0 & a \\ a^{\dagger} & 0 \end{pmatrix}$$

Corresponding eigensystem:

$$\Phi_{ns \uparrow m}(\mathbf{r}) = 2^{\frac{1}{2}(\delta_{n,0}-1)} \begin{pmatrix} s_n \phi_{|n|-1 \ m}(\mathbf{r}) \\ \phi_{|n| \ m}(\mathbf{r}) \end{pmatrix} \chi_s, \qquad \epsilon_n = \operatorname{sign}(n) \hbar \omega_c \sqrt{|n|}$$

Quantum numbers: $n = \dots, -1, 0, 1, \dots, m = 0, 1, \dots, \sigma = \uparrow, \downarrow, s = \uparrow, \downarrow$

• C.f. 2DEG

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$$\epsilon_n = \hbar \frac{eB}{mc} \left(n + \frac{1}{2} \right)$$



Self Energy Corrections to Cyclotron Resonance

- In 2DEG Kohn's theorem applies -CR independent of e-e interactions
- Doesn't hold for graphene e-e interactions very important
- LL energy renormalised by self energy corrections due to exchange with electrons below Fermi level
- Corrections to CR diverge logarithmically with the cut off



Seen experimentally: Z. Jiang *et al.*, PRL **98**, 197403 (2007)







$$\begin{split} \text{Connection to 2DEG} \\ \text{Connection to 2DEG} \\ \mathbb{V}_{rm1,N_{rm1,N_{sm2}}^{N_{rm1}^{m}}} &= \langle \Phi_{N_{1}rm_{1}^{m}}^{N_{rm1}^{m}} \Phi_{N_{sm2}} \rangle = \delta_{x_{1}x_{1}^{m}} \delta_{x_{2}x_{2}^{m}} \delta_{x_{2}^{m}} \delta_{x_{2}^{m}}$$

Which transitions are allowed?

In the dipole approximation, contribution to Hamiltonian from incoming circularly polarised light is

$$\delta H_{\pm} = \frac{ev_F \mathcal{E}}{i\omega c} e^{-i\omega t} \begin{pmatrix} \sigma_{\pm} & 0\\ 0 & \sigma_{\mp} \end{pmatrix}$$

 $\sigma_{\pm} = \sigma_{x} \pm i\sigma_{y}$ corresponds to left and right circularly polarised light







Which transitions should we take into account?

- Do calculations for sublevel filling factors of the zeroth LL.
- Infinitely many transitions with same M_z are mixed by Coulomb interactions
- Only consider mixing for those with the same energies strong magnetic field approx



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Numerical Considerations

- Matrix comes in 4x4 blocks
- Need to truncate at finite *m* ok, because only seek localised states
- Size limit imposed by calculating matrix elements with high order Laguerre polynomials, not by diagonalisation
- Use 4x50=200 basis elements
- Results stable wrt changing matrix size



In the Absence of an Impurity

A. Iyengar *et al.* PRB **75**, 125430 (2007); Yu. A. Bychkov and G. Martinez, PRB **77**, 125417 (2008)

- Use Landau gauge $\mathbf{A} = -\mathbf{B}y\hat{\mathbf{x}}$
 - $m \rightarrow k_y$
- Thickness of band is 0.75*E*₀ with

$$E_0 = \sqrt{\frac{\pi}{2}} \frac{e^2}{\varepsilon \ell_B}$$











Summary/Outlook

- Used a secondary quantised approach to determine collective excitations bound on an impurity in a single sheet of graphene in the presence of a strong perpendicular magnetic field [arXiv:0902.4176]
- Could our results be experimentally detected?

Only know relative strengths

- Could think about:
- rippling in graphene layer
- intervalley scattering
- nature of impurity
- First step towards combining work on magnetoplasma in pristine graphene and disordered graphene
- Could they enhance understanding of the nature of disorder in graphene?
- Further work:

Non integer filling factors: consider opposite limit of low electron density, so D- states are formed.





Thank you for listening



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Other work:

• Anderson transition in BCC and FCC lattices using transfer-matrix method [PRB **77**, 245117-8 (2008)]

• Excitonic storage in an Aharonov-Bohm nanoring with applied inplane electric field [PRL **102**, 096405 (2009)]



